

DOCKET NO: 240800US DIV

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF : DATE ALLOWED: JANUARY 25, 2006
NORIHISA ARAI : EXAMINER: ROSE, K.
SERIAL NO: 10/670,529 :
FILED: SEPTEMBER 26, 2003 : GROUP ART UNIT: 2822
FOR: SEMICONDUCTOR DEVICE :
INCLUDING IMPURITIES IN
SUBSTRATE VIA MOS TRANSISTOR
GATE ELECTRODE AND GATE
INSULATION FILM

COMMENTS ON STATEMENT OF REASONS FOR ALLOWANCE

COMMISSIONER FOR PATENTS
ALEXANDRIA, VIRGINIA 22313

SIR:

Applicant acknowledges with appreciation the indication of allowability of the claimed invention. In response to the Examiner's Statement of Reason for Allowance in the Notice of Allowance of January 25, 2006, Applicant respectfully submits the following comments.

On January 19, 2006, Applicants' representative authorized an Examiner's Amendment canceling Claims 21 and 26 and including this subject matter in Claims 19 and 24, respectively. However, in the Notice of Allowance of January 25, 2006, Claims 19 and 24 were amended to recite "the impurities are boron," rather than "the impurities include boron," as recited in Claims 21 and 26. Further, page 4 of the Notice of Allowance included a Statement of Reasons for Allowance that also referred to "the impurities are boron." As Claims 19 and 24 are amended herewith by the accompanying Amendment under 37 C.F.R.

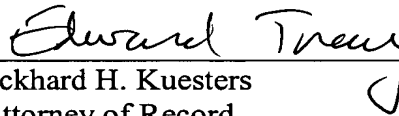
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Reply to Notice of Allowance of January 25, 2006

§1.312 to recite "the impurities include boron," with explicitly allows for other impurities besides boron, it is respectfully submitted that Claims 19 and 24 be construed according to the claim language provided in the accompanying Amendment under 37 C.F.R. §1.312.

Respectfully submitted,

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